

Data Provided: useful definitions and equations at end of paper (after Q4)

## DEPARTMENT OF ELECTRONIC AND ELECTRICAL ENGINEERING

Spring Semester 2007 - 2008 (2 hours)

## ANALOGUE CIRCUITS 1

Answer **THREE** questions. Solutions will be considered in the order in which they are presented in the answer book and **no marks will be awarded for an attempt at a fourth question.** Trial answers will be ignored if they are clearly crossed out. **The numbers given after each section of a question indicate the relative weighting of that section.** 

- 1 The input to the transformer of figure 1 is a 50Hz sinusoid and the secondary voltage is as shown.
  - (i) Sketch the waveforms you would expect to see at  $V_T$ ,  $V_{O1}$  and  $V_{O2}$ . Label times and amplitudes and take care to ensure the correct relative timings of your sketched waveforms. State any assumptions you have made about the diodes in the circuit.  $\{6\}$
  - (ii) What are the average values of the three waveforms of part (i)? {3}

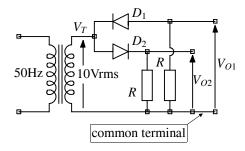
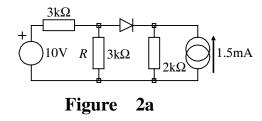


Figure 1

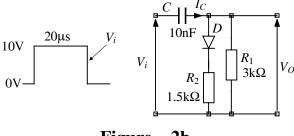
The resistors, R, are removed from figure 1 and replaced by loads that draw an approximately constant current of 100mA from  $V_{O1}$  and  $V_{O2}$ . These loads, however, require a supply with a ripple voltage no larger than 1V peak to peak, so smoothing capacitors must be added between each output line and the common terminal.

- (iii) Estimate a suitable value of smoothing capacitor for the  $V_{O1}$  and  $V_{O2}$  outputs. {3}
- (iv) Sketch the waveshape of the voltage you would expect to observe at  $V_{O1}$  after the capacitors have been added to figure 1, labelling peak values and ripple voltage. Assume that ideal components are used.  $\{2\}$
- (v) One quarter of the 100mA load current is drawn by a zener diode regulator circuit designed around a 9V zener diode with a zener slope resistance  $r_z$  of  $6\Omega$ . Calculate the value of resistor that must be between  $V_{O1}$  and the zener diode and estimate the ripple voltage superimposed on the regulated output.  $\{6\}$

- 2 (a) The diode in figure 2a has a forward voltage drop of 0.7V but is otherwise ideal.
  - **(i)** For the circuit of figure 2a, determine the conduction state of the diode and find either the forward conduction current through, or the reverse bias voltage across, the diode. {5}

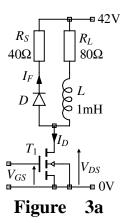


- (ii) If the 10V source is replaced by a variable source,  $V_1$ , sketch a graph of forward diode current,  $I_F$ , against  $V_1$  as  $V_1$  changes from 0V to +20V. Label the coordinates of the point where the diode changes state and label the slopes of straight line sections of your sketch. {5}
- **(b) (i)** The circuit of figure 2b consists initially of  $R_1$  and C. Sketch the  $V_O$  you would expect to observe in response to the input shown. Include on your sketch both the leading and trailing edge responses of the input pulse and label any time constants. {4}

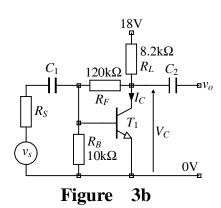


**Figure 2b** 

- $R_2$  and ideal diode D are now added to the circuit. Sketch the  $I_C$  that you would (ii) expect to observe in response to the input shown in figure 2b. Label your sketch with peak values and time constants. {6}
- 3 The MOSFET in figure 3a has an "on" state resistance of  $4\Omega$ . The (a) load for the switch is an actuator with resistive and inductive components,  $R_L$  and L. Assume that D has a forward voltage drop of 0.7V.
  - **(i)** what is the purpose of D? {2}
  - Calculate  $I_D$  assuming  $T_1$  has been "on" for a long time. {3} (ii)
  - (iii) Calculate the on-state power loss in  $T_1$ . {2}
  - What is the peak value of  $V_{DS}$  that will occur during the (iv) turn-off process? {4}



- **(b)** Work out the dc conditions  $V_C$  and  $I_C$  and the small **(i)** signal parameters  $g_m$  and  $r_{be}$  for the circuit of figure 3b. Make sure you state any assumptions and approximations that you use. Assume that  $V_{BE} = 0.7$ V and the b for  $T_1$  is 400. {5}
  - (ii) Draw a small signal equivalent circuit of the circuit of figure 3b.  $\{4\}$



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- 4 (a) Assuming that an ideal operational amplifier is available, sketch two circuit diagrams, one of a practically useful inverting amplifier circuit and one of a practically useful non-inverting amplifier circuit that each use the operational amplifier and two resistors. Be sure to indicate which circuit is which. Write down the voltage gain of each circuit in terms of the components you have used. {8}
  - **(b) (i)** Find  $v_o/v_i$  for the circuit of figure 4a.  $\{5\}$ 
    - (ii) Draw a circuit diagram of a simpler circuit that will achieve the same voltage gain. {2}

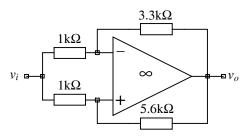


Figure 4a

(c) For the circuit of figure 4b, calculate the value of a that will make the sinusoidal component of  $v_o$  equal to zero.  $\{5\}$ 

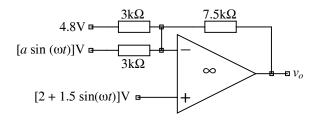


Figure 4b

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You may find some of the following relationships and definitions useful:

$$g_m = \frac{eI_C}{kT}$$
  $r_{be} = \frac{\beta}{g_m}$   $h_{FE} = \frac{I_C}{I_B}$   $\beta = \frac{\Delta I_C}{\Delta I_B} = \frac{i_c}{i_b}$   $\tau = RC$ 

$$I = C \frac{dV}{dt}$$
  $\omega = 2\pi f$   $V(t) = (V_{START} - V_{FINISH}) \exp\left(\frac{-t}{\tau}\right) + V_{FINISH}$ 

$$V_{AVE} = \frac{V_P}{\pi}$$
 for a half wave rectified sinusoid  $V_{rms} = \frac{V_P}{\sqrt{2}}$  for a sinusoid

$$v_o = A_v (v^+ - v^-)$$
  $\frac{kT}{e} = 0.026 V$ 

unit multipliers: 
$$p = x10^{-12}$$
,  $n = x10^{-9}$ ,  $\mu = x10^{-6}$ ,  $m = x10^{-3}$ ,  $k = x10^{3}$ ,  $M = x10^{6}$   $G = x10^{9}$ 

All the symbols have their usual meanings

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